Applicant: Shunpei Yamazaki et al.

Attorney's Docket No.: 07977-221004
Serial No.: 10/799 722

Client Ref.: US3523/3532D2C1

Serial No.: 10/799,722 Filed: March 15, 2004

Page : 2 of 6

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

- 1. (Canceled)
- 2. (Previously Presented) A portable phone comprising:
- a body;
- a semiconductor device contained in the body, said semiconductor device comprising:
 - a substrate;
 - a passive component including at least an inductor formed over the substrate;
 - an insulating film covering said passive component;
 - an insulation layer attached to said insulating film via an adhesive;
 - a circuit including at least one thin film transistor formed over said insulation

layer,

wherein said circuit is electrically connected to said passive component by at least one electrode through an opening of said insulation layer.

- 3. (Previously Presented) The portable phone according to claim 2 wherein said substrate is a quartz substrate.
- 4. (Previously Presented) The portable phone according to claim 2 wherein said insulation layer comprises aluminum nitride.
 - 5. (Previously Presented) A portable phone comprising:
 - a substrate;

Attorney's Docket No.: 07977-221004 Applicant: Shunpei Yamazaki et al. Client Ref.: US3523/3532D2C1

Serial No.: 10/799,722 : March 15, 2004 Filed

Page : 3 of 6

a passive component including at least a capacitor formed over the substrate;

an insulating film covering said passive component;

an insulation layer attached to said insulating film via a n adhesive;

a circuit including at least one thin film transistor formed over said insulation layer,

wherein said circuit is electrically connected to said passive component by at least one electrode through an opening of said insulation layer.

6. (Previously Presented) The portable phone according to claim 5 wherein said substrate is a quartz substrate.

- 7. (Previously Presented) The portable phone according to claim 5 wherein said insulation layer comprises aluminum nitride.
 - 8. (Previously Presented) A portable phone comprising:
 - a body; and
 - a semiconductor device contained in the body, said semiconductor device comprising:
 - a substrate;
 - a passive component including at least a SAW filter formed over the substrate;
 - an insulating film covering said passive component;
 - an insulation layer attached to said insulating film via an adhesive;
 - a circuit including at least one thin film transistor formed over said insulation

layer,

wherein said circuit is electrically connected to said passive component by at least one electrode through an opening of said insulation layer.

9. (Previously Presented) The portable phone according to claim 8 wherein said substrate is a quartz substrate.

Applicant: Shunpei Yamazaki et al.

Attorney's Docket No.: 07977-221004

Serial No.: 10/799 722

Client Ref.: US3523/3532D2C1

Serial No.: 10/799,722 Filed: March 15, 2004

Page : 4 of 6

10. (Previously Presented) The portable phone according to claim 8 wherein said layer comprises aluminum nitride.

11. (Previously Presented) A portable phone comprising:

a body; and

a semiconductor device contained in the body, said semiconductor device comprising:

a substrate;

a passive component including at least a band-pass filter formed over the substrate;

an insulating film covering said passive component;

an insulation layer attached to said insulating film via an adhesive;

a circuit including at least one thin film transistor formed over said insulation

layer,

wherein said circuit is electrically connected to said passive component by at least one electrode through an opening of said insulation layer.

- 12. (Previously Presented) The portable phone according to claim 11 wherein said substrate is a quartz substrate.
- 13. (Previously Presented) The portable phone according to claim 11 wherein said layer comprises aluminum nitride.
 - 14. (Currently Amended) A portable phone comprising:
 - a body; and
 - a semiconductor device contained in the body, said semiconductor device comprising:

a substrate;

an oscillating component formed over the substrate;

an insulating film covering said oscillating component;

Applicant: Shunpei Yamazaki et al.

Serial No.: 10/799,722 Filed: March 15, 2004

layer,

Page : 5 of 6

Attorney's Docket No.: 07977-221004 Client Ref.: US3523/3532D2C1

an insulation layer attached to said insulating film via an adhesive; a circuit including at least one thin film transistor formed over said insulation

wherein said circuit is electrically connected to said [[passive]] oscillating component by at least one electrode through an opening of said insulation layer.

- 15. (Previously Presented) The portable phone according to claim 14 wherein said substrate is a quartz substrate.
- 16. (Previously Presented) The portable phone according to claim 14 wherein said layer comprises aluminum nitride.

17-20. (Canceled)